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(REV. 7-80)U.S. DEPARTMENT OF COMMERCE  
PATENT AND TRADEMARK OFFICEATTY. DOCKET NO.  
**00P9119US**SERIAL NO.  
**TBD****LIST OF DOCUMENTS CITED BY APPLICANT**  
(Use several sheets if necessary)APPLICANT  
**Jingyu Lian, et al.**FILING DATE  
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## U.S. PATENT DOCUMENTS

| *EXAMINER<br>INITIAL |    | DOCUMENT<br>NUMBER | DATE | NAME | CLASS | SUBCLASS | FILING DATE<br>(IF APPROPRIATE) |
|----------------------|----|--------------------|------|------|-------|----------|---------------------------------|
|                      | AA |                    |      |      |       |          |                                 |
|                      | AB |                    |      |      |       |          |                                 |
|                      | AC |                    |      |      |       |          |                                 |
|                      | AD |                    |      |      |       |          |                                 |
|                      | AE |                    |      |      |       |          |                                 |
|                      | AF |                    |      |      |       |          |                                 |
|                      | AG |                    |      |      |       |          |                                 |
|                      | AH |                    |      |      |       |          |                                 |
|                      | AI |                    |      |      |       |          |                                 |
|                      | AJ |                    |      |      |       |          |                                 |
|                      | AK |                    |      |      |       |          |                                 |

## FOREIGN PATENT DOCUMENTS

|    |    | DOCUMENT<br>NUMBER | DATE                              | COUNTRY | CLASS | SUBCLASS | TRANSLATION |    |
|----|----|--------------------|-----------------------------------|---------|-------|----------|-------------|----|
|    |    |                    |                                   |         |       |          | YES         | NO |
| EO | AL | 10-242078          | Publication<br>Date:<br>9/11/1998 | Japan   |       |          | X           |    |
|    | AM |                    |                                   |         |       |          |             |    |
|    | AN |                    |                                   |         |       |          |             |    |

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

|    |    |  |  |  |  |  |  |  |
|----|----|--|--|--|--|--|--|--|
| EO | AO | D.E. Kotecki, et al., (Ba,Sr)TiO <sub>3</sub> dielectrics for future stacked-capacitor DRAM, IBJ J. Res. Develop, Vol. 43, No. 3, May 1999, pp. 367-379. |  |  |  |  |  |  |
|    | AP |  |  |  |  |  |  |  |
|    | AQ |  |  |  |  |  |  |  |

EXAMINER

*Edgardo Gutierrez*

DATE CONSIDERED

*6/6/02*

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